

STAC4932B

Datasheet - production data

HF/VHF/UHF RF power N-channel MOSFET



Figure 1. Pin connection



Features

- Excellent thermal stability
- Common source push-pull configuration
- P_{OUT} = 1000 W min. (1200 W typ.) with 26 dB gain @ 123 MHz
- Pulse conditions: 1 msec 10%
- In compliance with the 2002/95/EC European directive
- ST air-cavity STAC[®] packaging technology

Description

The STAC4932B is an N-channel MOS field-effect RF power transistor. It is intended for 100 V pulse applications up to 250 MHz. This device is suitable for use in industrial, scientific and medical applications. The STAC4932B benefits from the latest generation of efficient, patent-pending STAC[®] package technology.

Table 1. Device summary

| Order code | Marking | Package | Packaging |
|------------|-------------------------|----------|--------------|
| STAC4932B | STAC4932 ⁽¹⁾ | STAC244B | Plastic tray |

1. For more details please refer to Chapter 6: Marking, packing and shipping specifications.

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This is information on a product in full production.

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1 Electrical data

1.1 Maximum ratings

| Symbol | Parameter | Value | Unit | |
|-------------------------------------|------------------------------------------------|-------------|------|--|
| V _{(BR)DSS} ⁽¹⁾ | Drain source voltage | 200 | V | |
| V _{DGR} | Drain-gate voltage (R_{GS} = 1 M Ω) | 200 | V | |
| V _{GS} | Gate-source voltage | ±20 | V | |
| TJ | Max. operating junction temperature | 200 | °C | |
| T _{STG} | Storage temperature | -65 to +150 | °C | |
| T = 150 °C | | | | |

Table 2. Absolute maximum ratings (T_{CASE} = 25 °C)

1. T_J = 150 °C

1.2 Thermal data

Table 3. Thermal data (1 msec - 10%)

| Symbol | Parameter | Value | Unit |
|------------------------------------------------------|-----------|-------|------|
| R _{thJC} Junction - case thermal resistance | | 0.075 | °C/W |



2 Electrical characteristics

T_{CASE} = +25 °C

2.1 Static

| Table 4. Static (per side) | | | | | | | |
|-------------------------------------|-------------------------|--------------------------|-----------|-----|------|------|------|
| Symbol | | Test conditions | | | Тур. | Max. | Unit |
| V _{(BR)DSS} ⁽¹⁾ | $V_{GS} = 0 V$ | l _{DS} = 100 mA | | 200 | 250 | | V |
| I _{DSS} | $V_{GS} = 0 V$ | V _{DS} = 100 V | | | | 1 | mA |
| I _{GSS} | $V_{GS} = 20 V$ | $V_{DS} = 0 V$ | | | | 250 | nA |
| V _{TH} | I _D = 250 mA | | | 2.0 | | 4.0 | V |
| V _{DS(ON)} | V _{GS} = 10 V | I _D = 10 A | | | | 3.6 | V |
| G _{FS} | V _{DS} = 10 V | I _D = 2.5 A | | | 6 | | S |
| C _{ISS} | V _{GS} = 0 V | V _{DS} = 100 V | f = 1 MHz | | 570 | | pF |
| C _{OSS} | V _{GS} = 0 V | V _{DS} = 100 V | f = 1 MHz | | 134 | | pF |
| C _{RSS} | V _{GS} = 0 V | V _{DS} = 100 V | f = 1 MHz | | 8 | | pF |
| | | | | | | | |

Table 4. Static (per side)

1. T_J = 150 °C

2.2 Dynamic

| Table 5. Pulse / 1 msec - 10% | _ |
|-------------------------------|---|
| | Т |

| Symbol | Test conditions | Min. | Тур. | Max. | Unit |
|------------------|--------------------------------------------------------------------------------------------------|------|------|------|------|
| P _{OUT} | V _{DD} = 100 V, I _{DQ} = 2 x 250 mA, f = 123 MHz | 1000 | 1200 | - | W |
| h _D | V _{DD} = 100 V, I _{DQ} = 2 x 250 mA, P _{OUT} = 1000 W, f = 123 MHz | | 60 | - | % |
| Gain | V _{DD} = 100 V, I _{DQ} = 2 x 250 mA, P _{OUT} = 1000 W, f = 123 MHz | | 26 | - | dB |



3 Impedance



Table 6. Impedance data

| Freq. (MHz) | Z _{IN} (Ω) | Ζ_{DL}(Ω) |
|------------------|---------------------|---------------------------|
| 123 MHz (pulsed) | 1.3 - j 2.8 | 7.7 - j 9.4 |

Note: Measured gate-to-gate and drain-to-drain, respectively.



4 Typical performance



Figure 3. Maximum safe operating area









Figure 5. Transient thermal model







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Figure 7. Efficiency vs. output power



5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



Figure 8. Package dimensions



| | Table 7. STAC244E | | |
|------|-------------------|------|-------|
| Dim. | | mm | |
| 2 | Min. | Тур. | Max. |
| А | 5.08 | | 5.59 |
| A1 | 4.32 | | 4.83 |
| В | 4.32 | | 5.33 |
| С | 9.65 | | 9.91 |
| D | 17.78 | | 18.08 |
| E | 33.88 | | 34.19 |
| F | 0.10 | | 0.15 |
| G | | 1.02 | |
| Н | 1.45 | | 1.70 |
| I | 4.83 | | 5.33 |
| J | 9.27 | | 9.52 |
| К | 27.69 | | 28.19 |
| L | 3.12 | 3.23 | 3.33 |
| М | 3.35 | 3.45 | 3.56 |

Table 7. STAC244B mechanical data



6 Marking, packing and shipping specifications

| Order code | Packaging | Pcs per tray | Dry pack humidity | Lot code |
|------------|-----------|--------------|----------------------|-----------|
| STAC4932B | Tray | 20 | < 10% | Not mixed |

Figure 9. Marking layout



Table 9. Marking specifications

| Symbol | Description | |
|--------|--------------------------------|--|
| CZ | Assembly plant | |
| ZZZ | Last 3 digits of diffusion lot | |
| VY | Diffusion plant | |
| MAR | Country of origin | |
| CZ | Test and finishing plant | |
| у | Assembly year | |
| xx | Assembly week | |



7 Revision history

| Date | Revision | Changes |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------|
| 19-Feb-2010 | 1 | First release. |
| 26-May-2010 | 2 | Document status promoted from preliminary data to datasheet. |
| 03-Aug-2010 | 3 | Updated description on cover page and Table 3. |
| 03-Sep-2010 | 4 | Updated figures: 3, 4 and 5. |
| 12-Sep-2011 | 5 | Inserted new Section 6: Marking, packing and shipping specifications. Updated Table 6. Minor text changes. |
| 01-Jul-2013 | 6 | Modified pin labeling in <i>Figure 1: Pin connection</i> . Modified document title. Minor text corrections throughout document. |
| 27-Jan-2014 | 7 | Modified pin labeling in <i>Figure 1: Pin connection</i> . |

Table 10. Document revision history



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